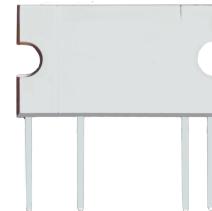


## YDS2/2A600V——2A 600V Opto-MOS

### 概述 Features

- 厚度3.0mm SSR Thickness 3.0mm SSR
- 负载电流最大为2A Max. load current 2A
- 击穿电压600V Breakdown voltage 600V
- 介质耐压3000V Dielectric strength 3000V
- 符合RoHS RoHS compliant

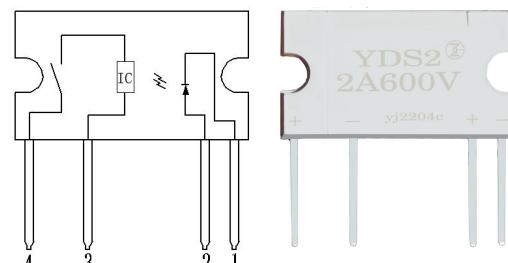


### 应用 Applications

- 测试设备 Measuring instruments
- 工业控制 Industrial control

### 打印标志 Marking information

Part number	Package	Marking
YDS2/2A600V	SIP4	YDS2 2A600V



### 极限值 Absolute maximum ratings

(Ta=25°C)

特性参数/Parameter	符号/Symbol	测试条件/Test condition	最小值/Min.	典型值/Typ.	最大值/Max.	单位/Unit
输入端/Input	LED 反向电压/LED reverse voltage	V <sub>R</sub>		6		V
	LED 正向电流/LED forward current	I <sub>F</sub>			50	mA
	功耗/Power dissipation	P <sub>in</sub>			75	mW
输出端/Output	击穿电压/ Breakdown voltage	BV <sub>DSS</sub>	600			V
	功耗/Power dissipation	P <sub>out</sub>			2	W
	额定电流/On-state current	I <sub>L</sub>	I <sub>in</sub> =10mA		2	A
	峰值电流/Peak current	I <sub>peak</sub>	10 ms (1shot), VL = DC	4		A
介质耐压/Dielectric strength *	V <sub>ISO</sub>	I <sub>ISO</sub> ≤0.3mA	3000			V <sub>rms</sub>
工作温度/Operating temperature	T <sub>opr</sub>		-30		85	°C
储存温度/Storage temperature	T <sub>stg</sub>		-40		125	°C

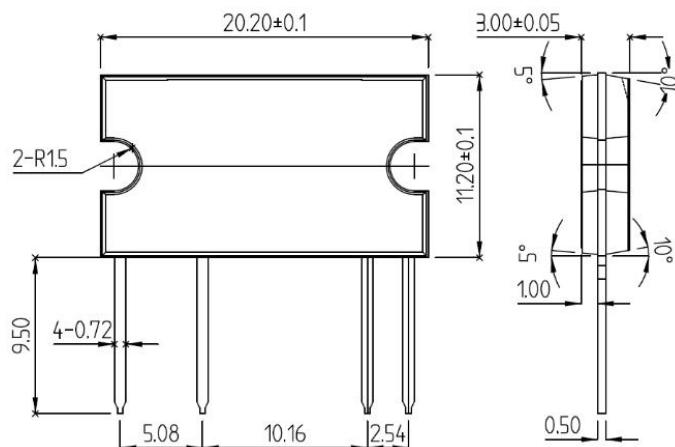
“\*”： RH=40 to 60%, T=20~30°C, AC for 1 minute.

## 电参数 Electrical parameters

特性参数/Parameter		符号/Symbol	测试条件/Test condition	最小值/Min.	典型值/Typ.	最大值/Max.	单位/Unit
输入端/Input	LED 正向电压/LED forward voltage	V <sub>f</sub>	I <sub>f</sub> =10mA		1. 2	1. 3	V
	LED 反向电流/LED reverse current	I <sub>R</sub>	V <sub>R</sub> =5V			10	μA
输出端/Output	断态泄漏电流/Output off-state leakage current	I <sub>Leak</sub>	V <sub>0</sub> =600V			5	μA
耦合特性/Transfer characteristics	LED 触发电流/LED trigger current	I <sub>PT</sub>			3	8	mA
	推荐的工作电流/Recommend operating current	I <sub>in</sub>		10		18	mA
	导通电阻/Output on-state resistance	R <sub>on</sub>	I <sub>in</sub> =10mA, I <sub>D</sub> =2A			0. 5	Ω
	导通时间/Turn on time	t <sub>on</sub>	I <sub>in</sub> =10mA, I <sub>D</sub> =1. 0A			5	ms
	关断时间/Turn off time	t <sub>off</sub>	I <sub>in</sub> =10mA, I <sub>D</sub> =1. 0A			2	ms
	电容/I/O capacitance	C				10	pF

### 外形尺寸 Outline dimension :mm

SIP4

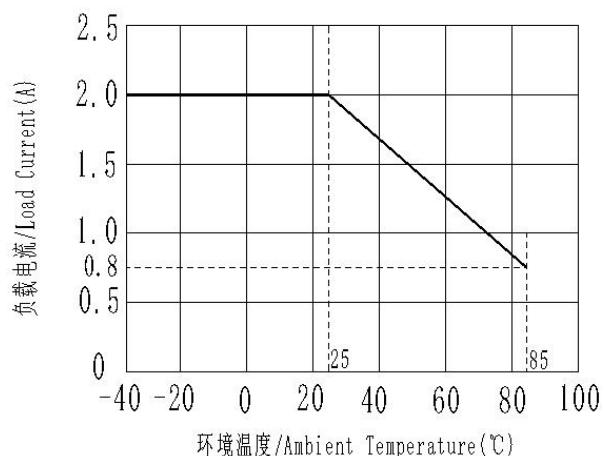


## 订货信息 Ordering information

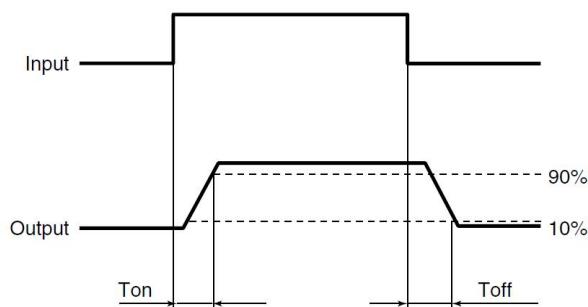
订货信息/Ordering information					
	Y	DS	2/	2A	600V
公司商标代号 Company symbol					
光功率 MOS SSR: Opto-power MOS SSR					
封装 Package: 2: SIP4					
负载电流 Load current: 2A					
击穿电压 BV <sub>DS</sub> : 600V					

## 特性曲线 Characteristic data

1. 负载电流与环境温度关系曲线  
Load current VS. ambient temperature

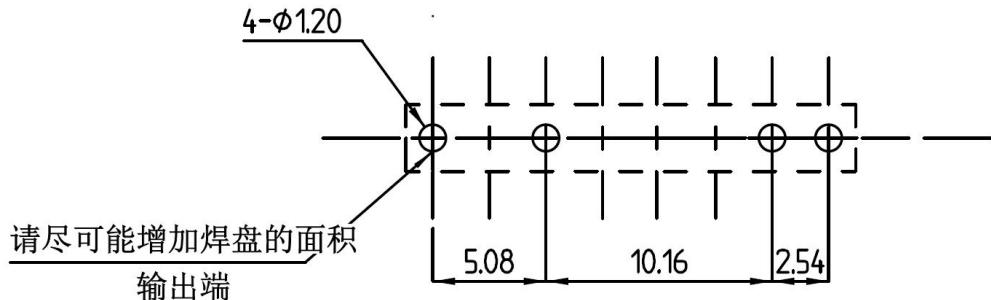


## 接通和关断时间关系 Turn on and turn off time



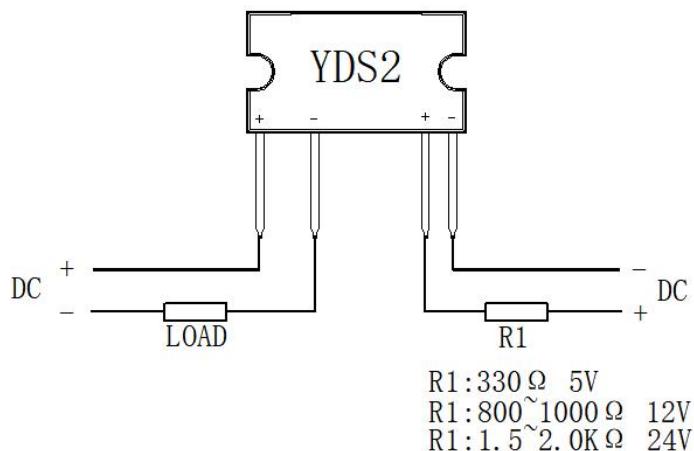
## 安装孔尺寸图 Fixing layout

Unit:mm



Please enlarge the solder pads of output.

## 接线图 Wiring diagram



## 注意事项 Notes

a) 工作环境温度超过 25℃时请降额使用。参见特性曲线。

When ambient temperature is above 25°C, the load current must be reduced. (see characteristic data)

b) 继电器接线时，务必保证输入端极性的正确，以免损坏继电器。

Ensuring the polarity is correct when connecting the input lines, otherwise the wrong connection will damage the relay.

## 关于防静电对策 Cautions for static electricity

a. 操作 MOS 输出继电器的作业人员，请穿戴制电性作业服，通过  $500k\Omega \sim 1M\Omega$  左右的保护电阻，实施人体接地。Employees handling relays should wear anti-static clothing and should be grounded through protective resistance of  $500k\Omega$  to  $1M\Omega$ .

- b. 请在作业台上装有带导电性的金属板或具有防静电的专用板，并对测量仪器和治具等实施接地。A conductive metal sheet should be placed over the work table. Measuring instruments and jigs should be grounded.
- c. 使用电烙铁时，对电烙铁前端进行接地。（建议使用低电压用的电烙铁。）When using soldering irons, either use irons with low leakage current, or ground the tip of the soldering iron. (Use of low-voltage soldering irons is also recommended.)
- d. 组装时使用的设备等也应正确地接地。Devices and equipment used in assembly should also be grounded.
- e. 对印刷电路板和机器进行包装时，请避免使用发泡苯乙烯、聚乙烯等带电性的高分子材料。When packing printed circuit boards and equipment, avoid using high-polymer materials such as foam styrene, plastic, and other materials which carry an electrostatic charge.
- f. 对MOS输出继电器进行储存和搬运时，请在不易产生静电的环境(例如湿度45~60%)中通过导电性包装材料进行保护。When storing or transporting relays, the environment should not be conducive to generating static electricity (for instance, the humidity should be between 45 and 60%), and relays should be protected using conductive packing materials.